

Triacs

BT137 series

GENERAL DESCRIPTION

Glass passivated triacs in a plastic envelope, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

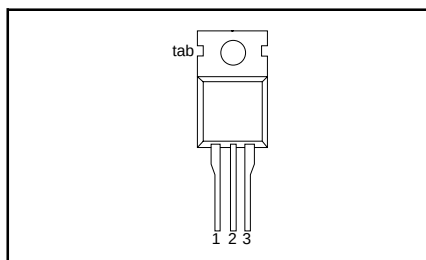
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
		500	600	800	
		500F	600F	800F	
		500G	600G	800G	
V_{DRM}	Repetitive peak off-state voltages	500	600	800	V
$I_{\text{T(RMS)}}$	RMS on-state current	8	8	8	A
I_{TSM}	Non-repetitive peak on-state current	65	65	65	A

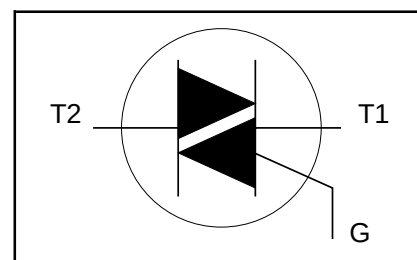
PINNING - TO220AB

PIN	DESCRIPTION
1	main terminal 1
2	main terminal 2
3	gate
tab	main terminal 2

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
V_{DRM}	Repetitive peak off-state voltages		-	-500 500 ¹	-600 600 ¹	-800 800	V
$I_{\text{T(RMS)}}$	RMS on-state current	full sine wave; $T_{\text{mb}} \leq 102^\circ\text{C}$	-	8			A
I_{TSM}	Non-repetitive peak on-state current	full sine wave; $T_{\text{j}} = 25^\circ\text{C}$ prior to surge	-	65			A
		$t = 20\text{ ms}$	-	71			A
		$t = 16.7\text{ ms}$	-	21			A
		$t = 10\text{ ms}$	-				A ² s
I^2t	I^2t for fusing		-				A ² s
di_{T}/dt	Repetitive rate of rise of on-state current after triggering	$I_{\text{TM}} = 12\text{ A}$; $I_{\text{G}} = 0.2\text{ A}$; $di_{\text{G}}/dt = 0.2\text{ A}/\mu\text{s}$	-	50			A/ μs
		T2+ G+	-	50			A/ μs
		T2+ G-	-	50			A/ μs
		T2- G-	-	10			A/ μs
		T2- G+	-	2			A
I_{GM}	Peak gate current		-	5			V
V_{GM}	Peak gate voltage		-	5			W
P_{GM}	Peak gate power		-	0.5			W
$P_{\text{G(AV)}}$	Average gate power	over any 20 ms period	-	150			°C
T_{stg}	Storage temperature		-40	125			°C
T_{j}	Operating junction temperature		-				°C

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 A/ μs .

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base	full cycle	-	-	2.0	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	half cycle	-	-	2.4	K/W
		in free air	-	60	-	K/W

STATIC CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.			UNIT
I_{GT}	Gate trigger current	BT137- $V_D = 12\ \text{V}; I_T = 0.1\ \text{A}$			...	...F	...G	
		T2+ G+	-	5	35	25	50	mA
		T2+ G-	-	8	35	25	50	mA
		T2- G-	-	11	35	25	50	mA
I_L	Latching current	$V_D = 12\ \text{V}; I_{GT} = 0.1\ \text{A}$						
		T2- G+	-	30	70	70	100	mA
		T2+ G+	-	7	30	30	45	mA
		T2+ G-	-	16	45	45	60	mA
I_H	Holding current	$V_D = 12\ \text{V}; I_{GT} = 0.1\ \text{A}$						
		T2- G-	-	5	30	30	45	mA
		T2- G+	-	7	45	45	60	mA
			-	5	20	20	40	mA
V_T	On-state voltage	$I_T = 10\ \text{A}$	-	1.3	1.65			V
V_{GT}	Gate trigger voltage	$V_D = 12\ \text{V}; I_T = 0.1\ \text{A}$	-	0.7	1.5			V
		$V_D = 400\ \text{V}; I_T = 0.1\ \text{A};$ $T_j = 125\ ^\circ\text{C}$	0.25	0.4	-			V
I_D	Off-state leakage current	$V_D = V_{DRM(max)};$ $T_j = 125\ ^\circ\text{C}$	-	0.1	0.5			mA

DYNAMIC CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.			TYP.	MAX.	UNIT
dV_D/dt	Critical rate of rise of off-state voltage	BT137- $V_{DM} = 67\% V_{DRM(max)};$ $T_j = 125\ ^\circ\text{C};$ exponential waveform; gate open circuit	...	...F	...G	250	-	V/ μs
dV_{com}/dt	Critical rate of change of commutating voltage	$V_{DM} = 400\ \text{V}; T_j = 95\ ^\circ\text{C};$ $I_{T(RMS)} = 8\ \text{A};$ $dl_{com}/dt = 3.6\ \text{A/ms};$ gate open circuit	-	-	10	20	-	V/ μs
t_{gt}	Gate controlled turn-on time	$I_{TM} = 12\ \text{A}; V_D = V_{DRM(max)};$ $I_G = 0.1\ \text{A}; dl_G/dt = 5\ \text{A}/\mu\text{s}$	-	-	-	2	-	μs

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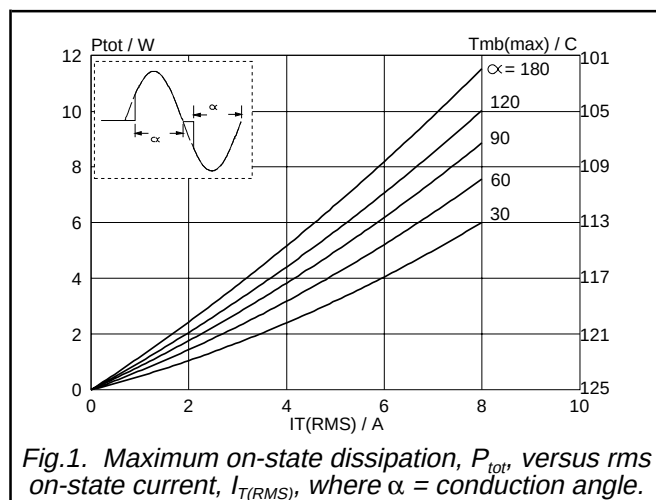


Fig.1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where α = conduction angle.

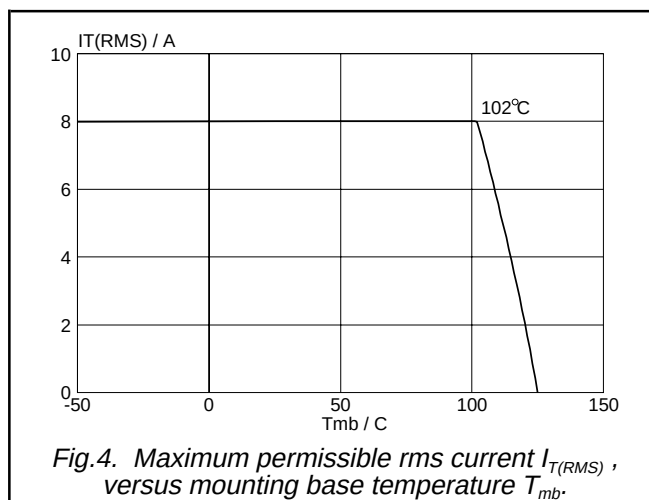


Fig.4. Maximum permissible rms current $I_{T(RMS)}$, versus mounting base temperature T_{mb} .

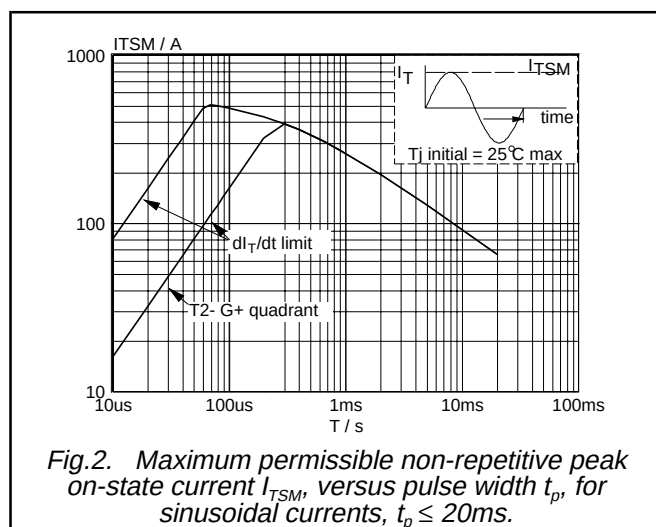


Fig.2. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \leq 20\text{ms}$.

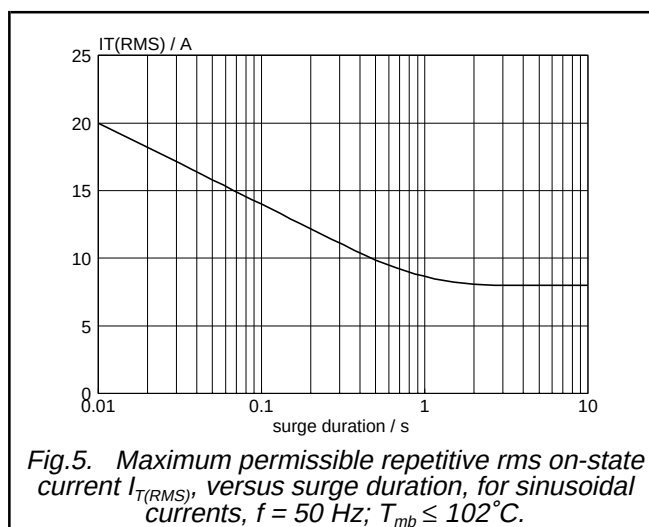


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, $f = 50\text{ Hz}$; $T_{mb} \leq 102^\circ\text{C}$.

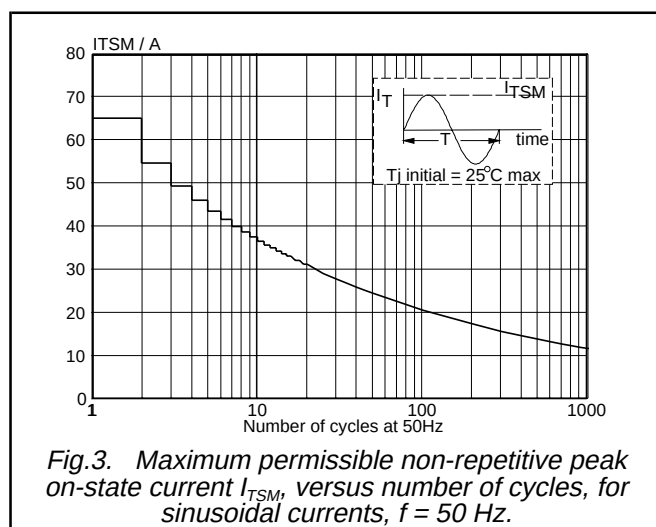


Fig.3. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus number of cycles, for sinusoidal currents, $f = 50\text{ Hz}$.

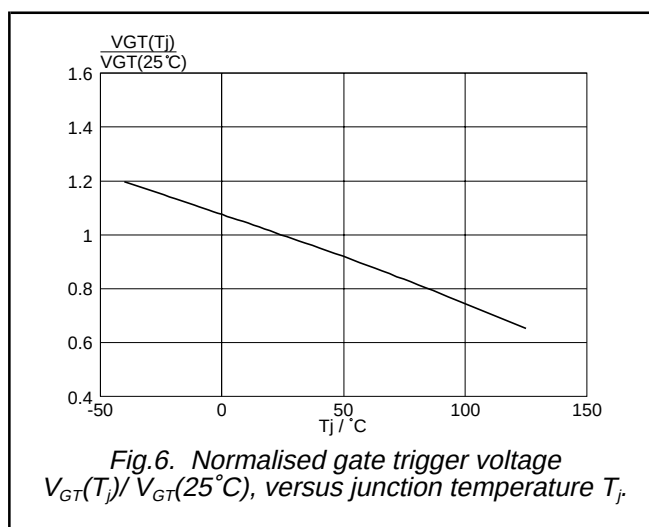
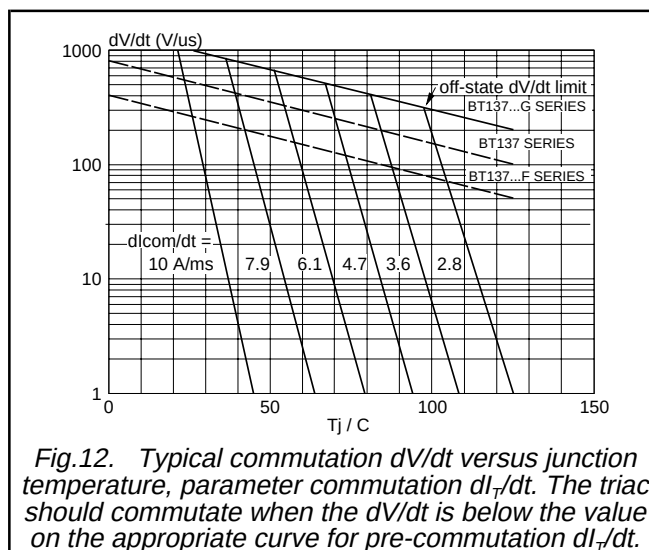
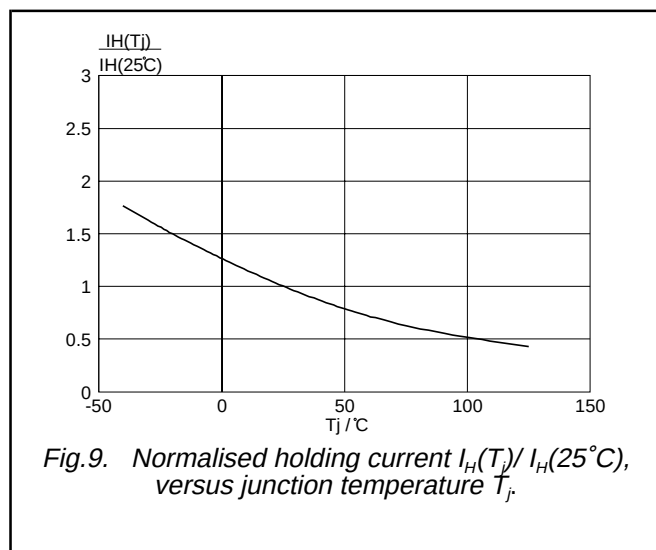
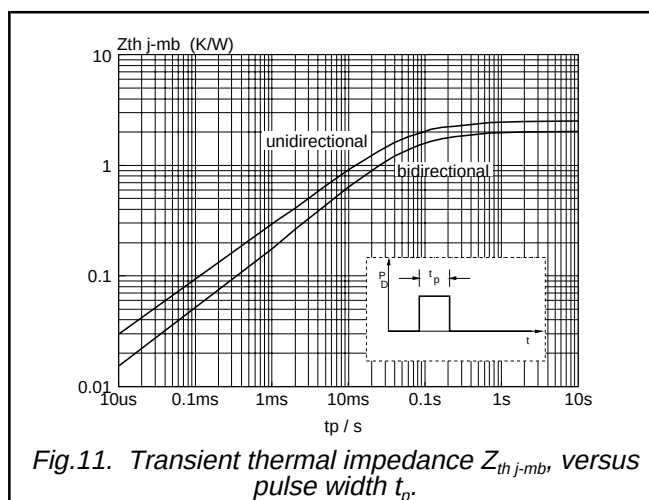
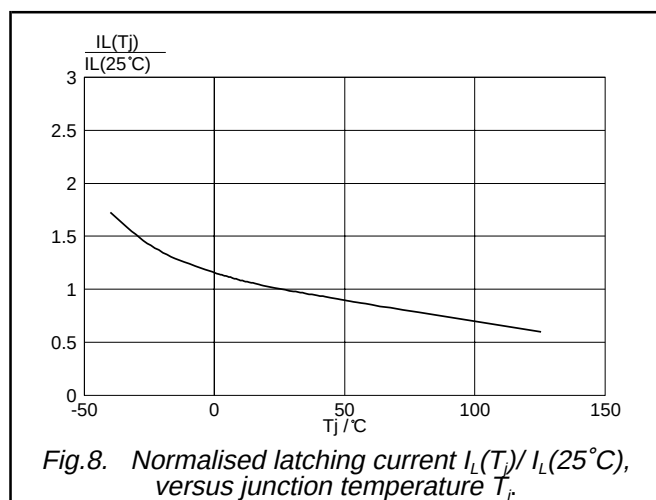
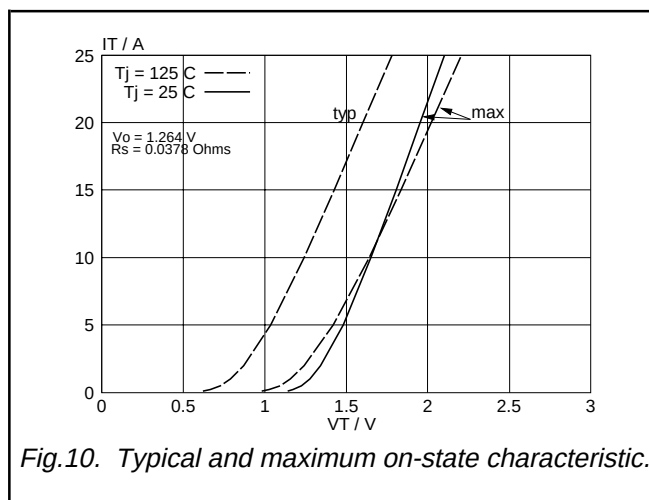
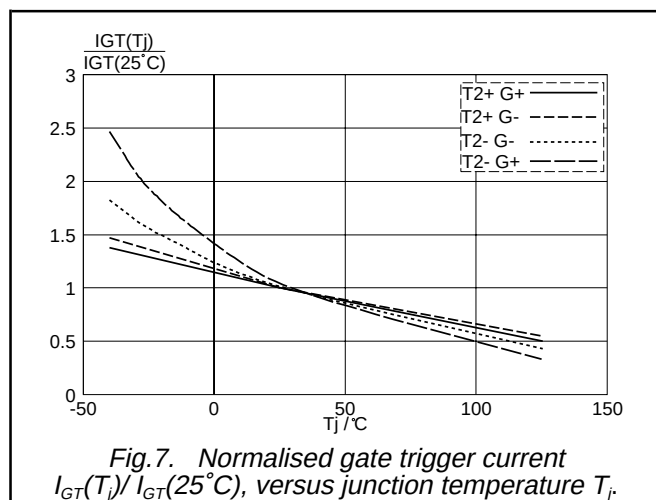


Fig.6. Normalised gate trigger voltage $V_{GT}(T_j) / V_{GT}(25^\circ\text{C})$, versus junction temperature T_j .

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MECHANICAL DATA

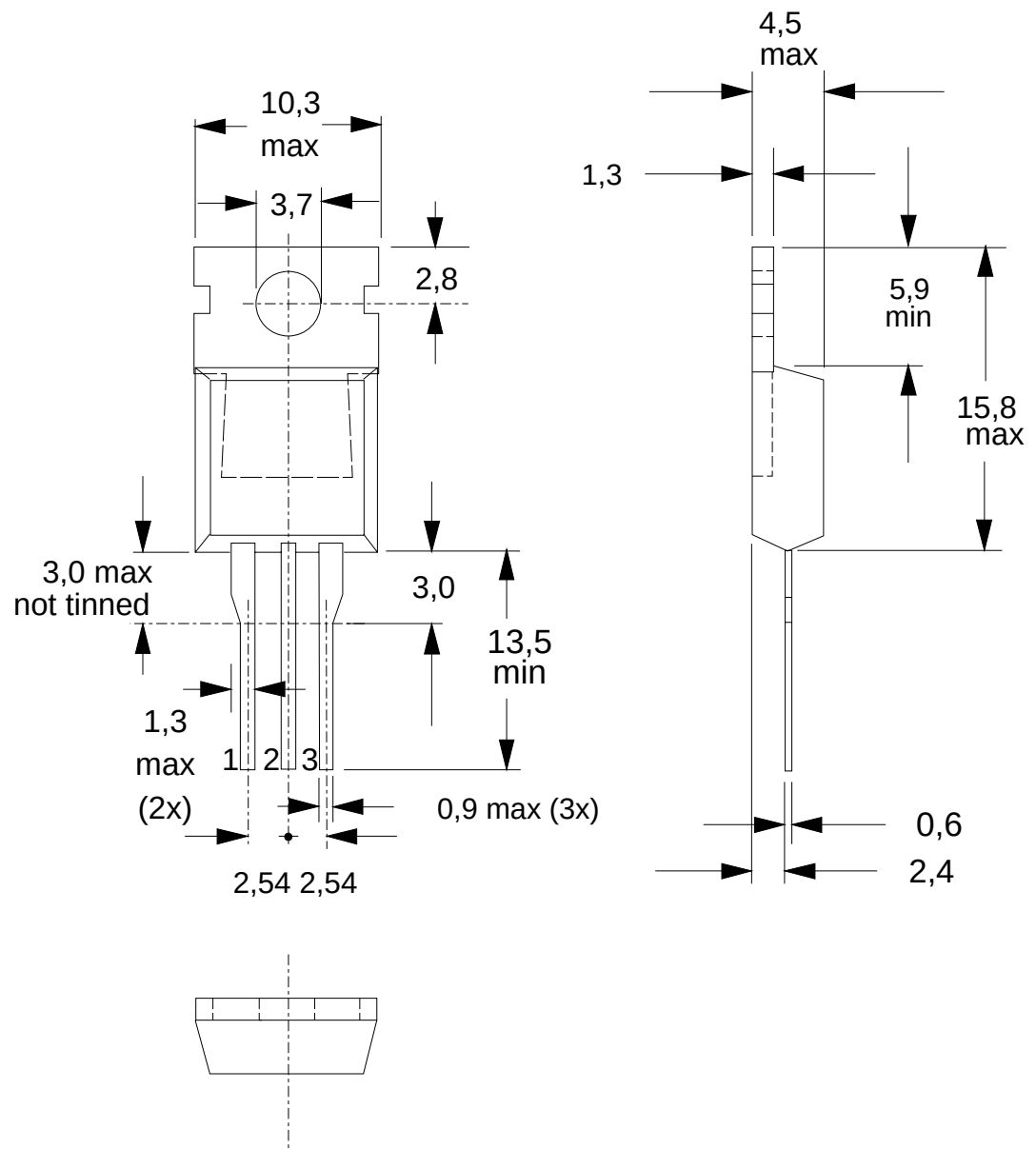
*Dimensions in mm**Net Mass: 2 g*

Fig.13. TO220AB; pin 2 connected to mounting base.

Notes

1. Refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".